



PJQ2460

60V N-Channel Enhancement Mode MOSFET

Voltage	60 V	Current	3.2A
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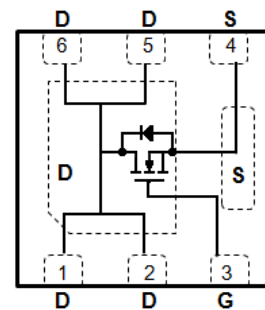
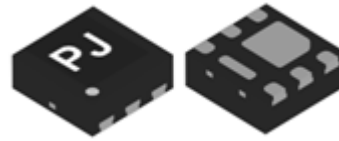
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@3.2A < 75m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@2.0A < 90m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in comply with EU RoHS 2011/65/EU directives.
- Green molding compound as per IEC61249 Std.
(Halogen Free)

Mechanical Data

- Case: DFN2020B-6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Marking: 460

DFN2020B-6L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current		I_D	3.2	A
Pulsed Drain Current		I_{DM}	12.8	A
Power Dissipation	$T_a=25^\circ C$	P_D	2.0	W
	Derate above $25^\circ C$		16	mW/ $^\circ C$
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal Resistance		$R_{\theta JA}$	62.5	$^\circ C/W$
- Junction to Ambient, $t < 10s$ (Note 3)				



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.8	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=3.2A$	-	53	75	m Ω
		$V_{GS}=4.5V, I_D=2.0A$	-	61	90	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=48V, V_{GS}=0V$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	$V_{DS}=48V, I_D=3.0A,$ $V_{GS}=10V$ (Note 1,2)	-	9.3	-	nC
Gate-Source Charge	Q_{gs}		-	2.2	-	
Gate-Drain Charge	Q_{gd}		-	1.9	-	
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	509	-	pF
Output Capacitance	C_{oss}		-	47	-	
Reverse Transfer Capacitance	C_{rss}		-	23	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=30V, I_D=3.0A,$ $V_{GS}=10V,$ $R_G=3.3\Omega$ (Note 1,2)	-	3.2	-	ns
Turn-On Rise Time	t_r		-	9.7	-	
Turn-Off Delay Time	$t_{d(off)}$		-	18.5	-	
Turn-Off Fall Time	t_f		-	6.4	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	3.2	A
Diode Forward Voltage	V_{SD}	$I_S=1A, V_{GS}=0V$	-	0.75	1.2	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. Repetitive rating, pulse width limited by junction temperature $T_J(\text{MAX})=150^\circ\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^\circ\text{C}$.
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.



PJQ2460

TYPICAL CHARACTERISTIC CURVES

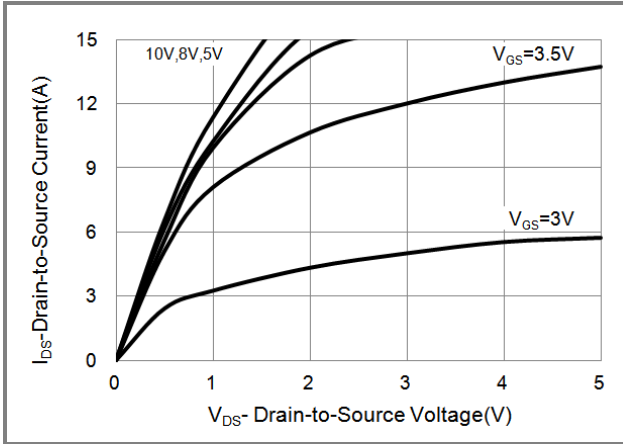


Fig.1 On-Region Characteristics

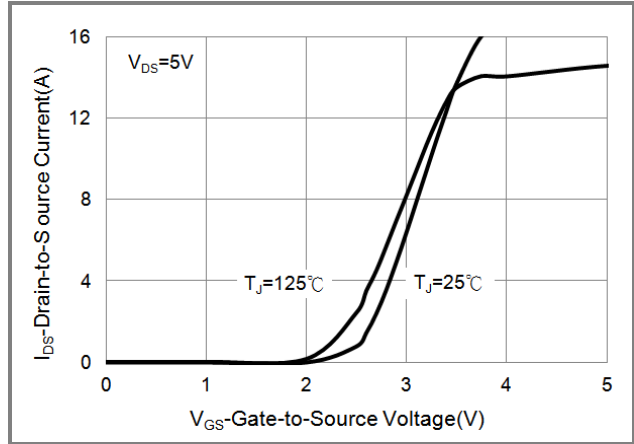


Fig.2 Transfer Characteristics

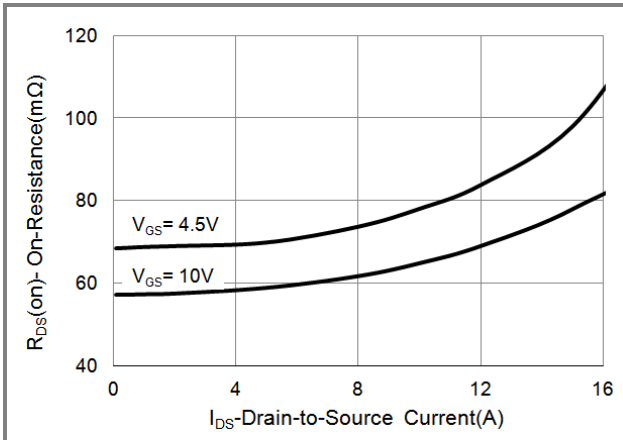


Fig.3 On-Resistance vs. Drain Current

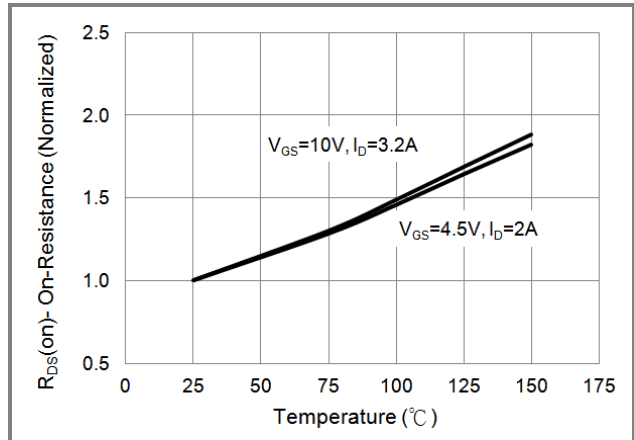


Fig.4 On-Resistance vs. Junction temperature

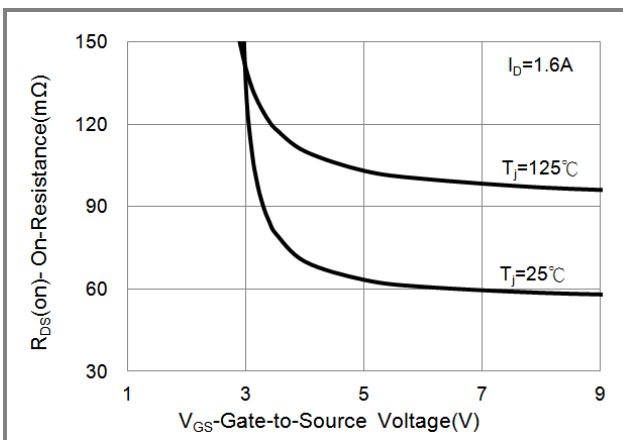


Fig.5 On-Resistance Variation with VGS.

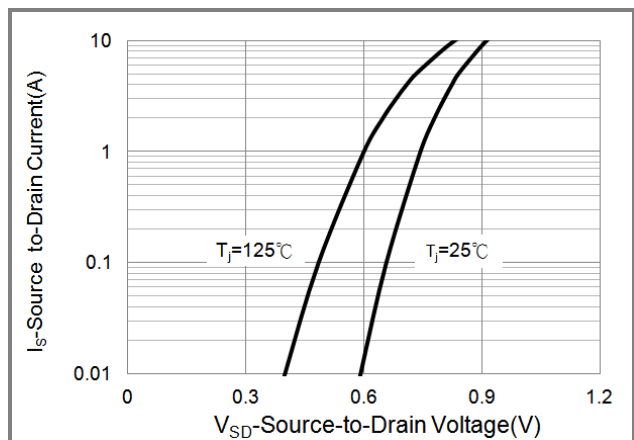


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

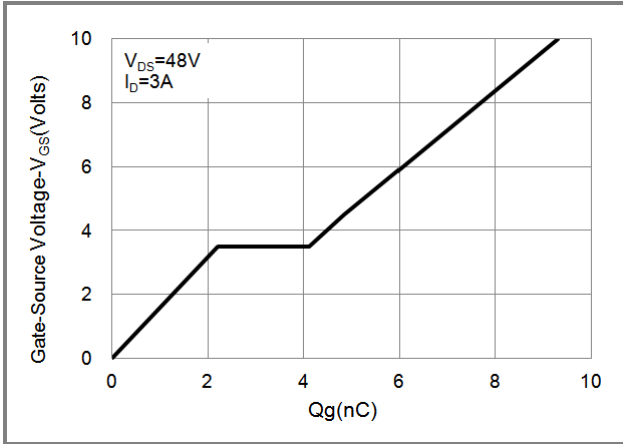


Fig.7 Gate-Charge Characteristics

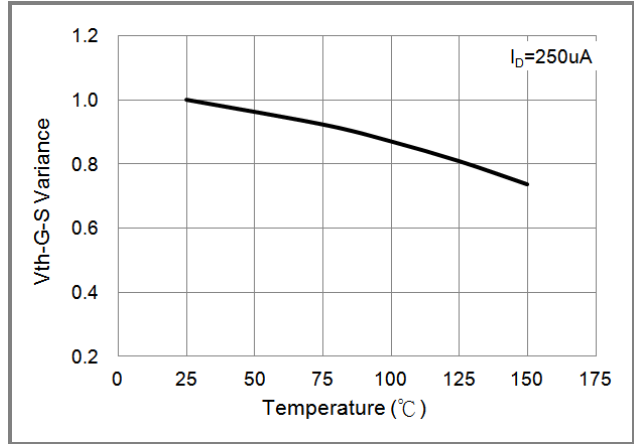


Fig.8 Threshold Voltage Variation with Temperature.

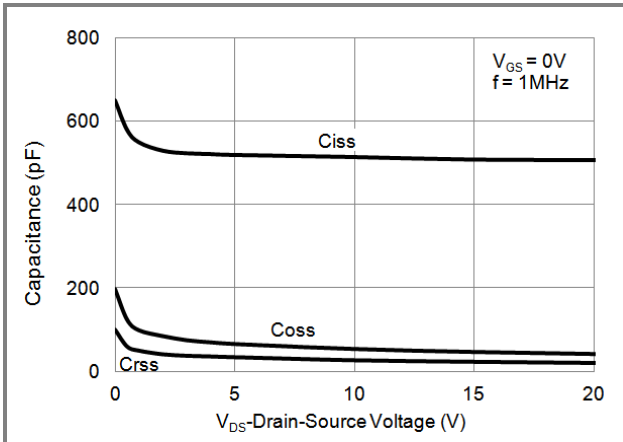


Fig.9 Capacitance vs. Drain-Source Voltage.

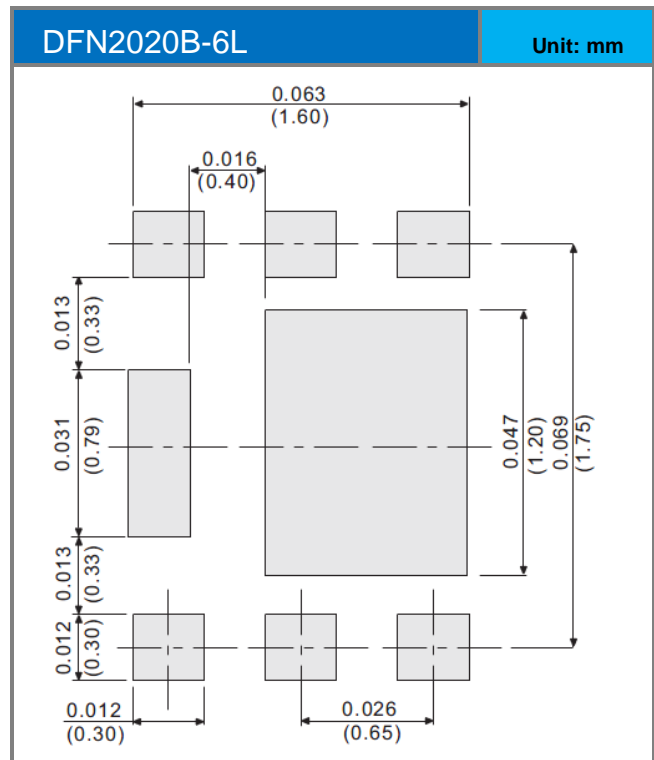
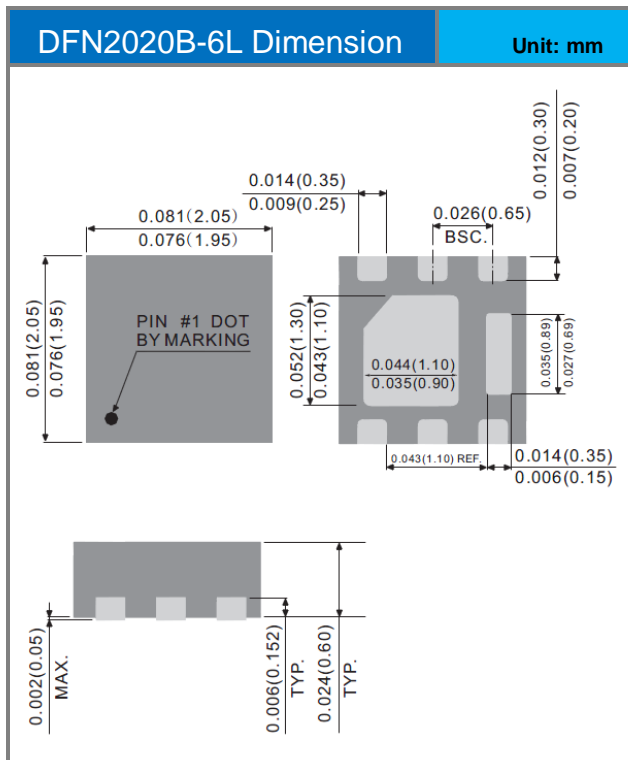


PJQ2460

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJQ2460_R1_00001	DFN2020B-6L	3K pcs / 7" reel	460	Halogen free

MOUNTING PAD LAYOUT





PJQ2460

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